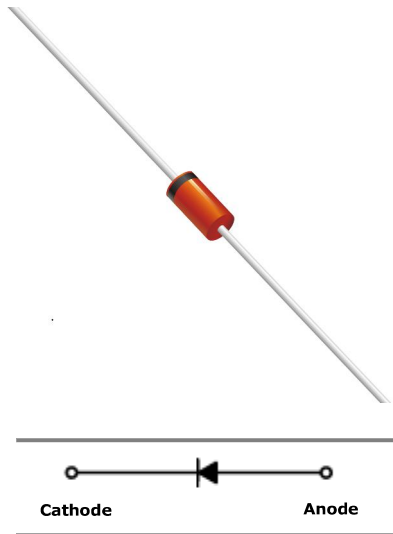
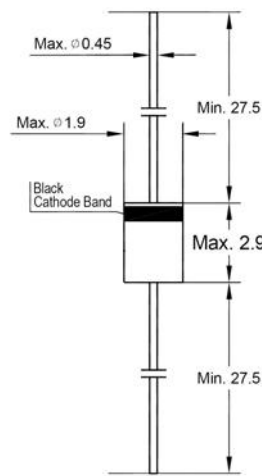


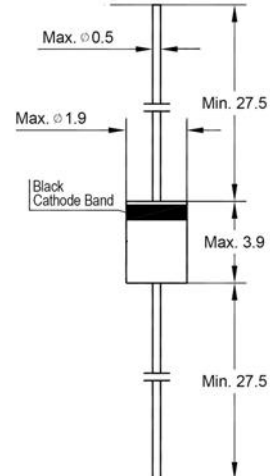


DO-34



Dimensions in mm

DO-35



Dimensions in mm

Absolute Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
P_D	Power Dissipation	500	mW
T_{STG}	Storage Temperature Range	-65 to +150	$^\circ\text{C}$
T_J	Operating Junction Temperature	+150	$^\circ\text{C}$
W_{IV}	Working Inverse Voltage	75	V
I_O	Average Rectified Current	150	mA
I_{FM}	Non-repetitive Peak Forward Current	450	mA
I_{FSURGE}	Peak Forward Surge Current (Pulse Width = 1.0 μsecond)	2	A

These ratings are limiting values above which the serviceability of the diode may be impaired.

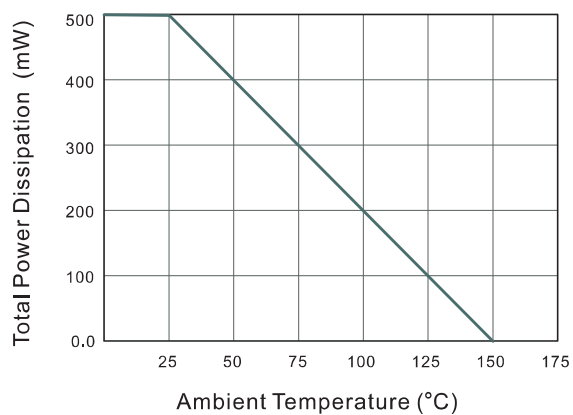
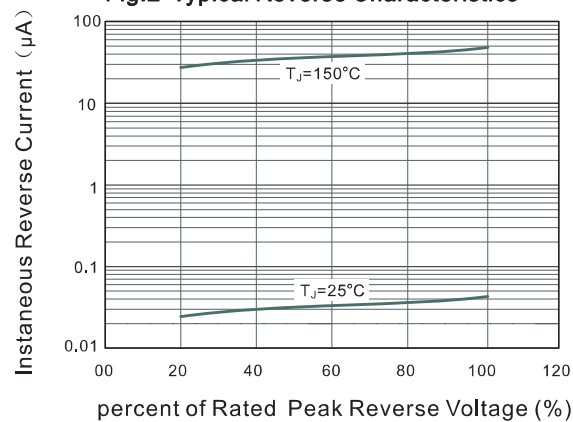
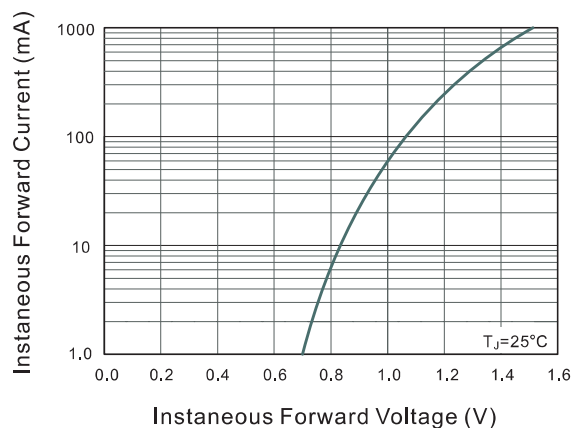
Specification Features:

- Fast Switching Device ($T_{RR} < 4.0 \text{ nS}$)
- Hermetically Sealed Glass
- RoHS Compliant
- Matte Tin (Sn) Terminal Finish
- Color band Indicates Negative Polarity

Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Limits		Unit
			Min	Max	
B_V	Breakdown Voltage	$I_R = 100 \mu\text{A}$	100		Volts
		$I_R = 5 \mu\text{A}$	75		
I_R	Reverse Leakage Current	$V_R = 20\text{V}$		25	nA
		$V_R = 75\text{V}$		5	μA
V_F	Forward Voltage	$I_F = 5\text{mA}$	0.62	0.72	Volts
		$I_F = 10\text{mA}$		1.0	
		$I_F = 100\text{mA}$		1.0	
T_{RR}	Reverse Recovery Time	$I_F = 10\text{mA}$, $V_R = 6\text{V}$ $R_L = 100\Omega$ $I_{RR} = 1\text{mA}$		4	nS
C	Capacitance	$V_R = 0\text{V}$, $f = 1\text{MHz}$		4	pF

Typical Characteristics

Fig.1 Power Derating Curve

Fig.2 Typical Reverse Characteristics

Fig.3 Typical Instantaneous Forward Characteristics

Fig.4 Typical Junction Capacitance
